









**SN54AHC08, SN74AHC08** 

ZHCSSG5L - OCTOBER 1995 - REVISED FEBRUARY 2024

# SNx4AHC08 四路双输入正与门

## 1 特性

- 2V至 5.5V的工作范围
- 闩锁性能超过 250mA,符合 JESD 17 规范
- ESD 保护性能超过 JESD 22 规范要求

## 2 应用

- 服务器
- 网络交换机
- PC 和笔记本电脑
- 电子销售终端

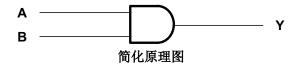
### 3 说明

SNx4AHC08 器件是四路双输入正与门。此类器件以正 逻辑执行布尔函数  $Y = A \cdot B$  或  $Y = \overline{A + B}$ 。

#### **哭**件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸 <sup>(2)</sup>
	D ( SOIC , 14 )	8.65mm × 3.90mm
	DB ( SSOP , 14 )	6.20mm × 5.30mm
	DGV ( TVSOP , 14 )	3.60mm × 4.40mm
SN74AHC08	N ( PDIP , 14 )	19.30mm × 6.35mm
	NS ( SO , 14 )	10.30mm × 5.30mm
	PW ( TSSOP , 14 )	5.00mm × 4.40mm
	RGY ( VQFN , 14 )	3.50mm x 3.50mm
	BQA ( WQFN , 14 )	3mm × 2.5mm
SN54AHC08	FK ( LCCC , 20 )	8.89mm × 8.89mm

- 更多相关信息,请参阅第11节。
- 封装尺寸(长×宽)为标称值,不包括引脚。



English Data Sheet: SCLS236



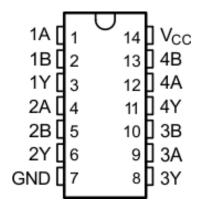
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## **4 Pin Configuration and Functions**



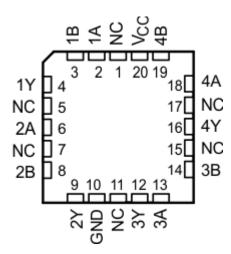


图 4-1. D, DB, DGV, N, NS, PW, or W Package 14-Pin SOIC, SSOP, TVSOP, PDIP, SO, or TSSOP (Top View)

图 4-2. FK Package 20-Pin LCCC (Top View)

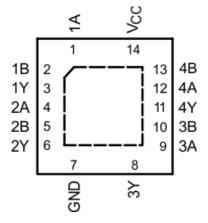


图 4-3. RGY or BQA Package 14-Pin VQFN or WQFN (Top View)



#### 表 4-1. Pin Functions

		PIN			
NAME	SOIC, SSOP, TVSOP, PDIP, SO, TSSOP	VQFN, WQFN	LCCC	I/O	DESCRIPTION
1A	1	1	2	I	1A Input
1B	2	2	3	1	1B Input
1Y	3	3	4	0	1Y Output
2A	4	4	6	I	2A Input
2B	5	5	8	I	2B Input
2Y	6	6	9	0	2Y Output
3Y	8	8	12	0	3Y Output
3A	9	9	13	I	3A Input
3B	10	10	14	I	3B Input
4Y	11	11	16	0	4Y Output
4A	12	12	18	I	4A Input
4B	13	13	19	I	4B Input
GND	7	7	10	_	Ground Pin
NC	_	_	1, 5, 7, 11, 15, 17	_	No Connection
V <sub>CC</sub>	14	14	20	_	Power Pin

English Data Sheet: SCLS236



#### **5 Specifications**

## 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		- 0.5	7	V
VI	Input voltage <sup>(2)</sup>		- 0.5	7	V
Vo	Output voltage, V <sub>O</sub> <sup>(2)</sup>		- 0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
TJ	Junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		- 65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 5.2 ESD Ratings

				VALUE	UNIT
		ectrostatic	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
'	<sup>(ESD)</sup> dis	<sup>0)</sup> discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.

#### **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	V
		V <sub>CC</sub> = 2 V	1.5		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 3V	2.1		V
		V <sub>CC</sub> = 5.5 V	3.85		
		V <sub>CC</sub> = 2 V		0.5	
V <sub>IL</sub>	Low-level Input voltage	V <sub>CC</sub> = 3 V		0.9	V
		V <sub>CC</sub> = 5.5 V		1.65	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V		- 50	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 3.3 V ± 0.3 V		- 4	mA
		V <sub>CC</sub> = 5 V ± 0.5 V		- 8	
		V <sub>CC</sub> = 2 V		50	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 3.3 V ± 0.3 V		4	mA
		V <sub>CC</sub> = 5 V ± 0.5 V		8	
Δ t/ Δ v	Input Transition rise or fall rate	V <sub>CC</sub> = 3.3 V ± 0.3 V		100	ns/V
	input transition use of fall rate	V <sub>CC</sub> = 5 V ± 0.5 V		20	115/ V

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<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.



over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
T <sub>A</sub> Operating free-air temperature	- 55	125	°C
SN74AHC08	- 40	125	C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

#### **5.4 Thermal Information**

		SN74AHC08								
	THERMAL METRIC <sup>(1)</sup>	D (SOIC)	DB (SSOP)	DGV (TVSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	RGY (VQFN)	BQA (WQFN)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
R <sub>θ</sub> ,	Junction-to-ambient thermal resistance	124.5	96	127	80	76	147.7	87.1	88.3	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

## 5.5 Electrical Characteristics, $T_A = 25$ °C

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
		2 V	1.9	2		
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		
$V_{OH}$		4.5 V	4.4	4.5		V
	I <sub>OH</sub> = -4 mA	3 V	2.58			
	I <sub>OH</sub> = -8 mA	4.5 V	3.94			
		2 V			0.1	
	I <sub>OL</sub> = 50 μA	3 V			0.1	
V <sub>OL</sub>		4.5 V			0.1	V
	I <sub>OH</sub> = 4 mA	3 V			0.36	
	I <sub>OH</sub> = 8 mA	4.5 V			0.36	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			2	μA
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		4	10	pF



## 5.6 Electrical Characteristics, T<sub>A</sub> = -55°C to 125°C

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	SN54AHC08	UNIT
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN MAX	UNII
		2 V	1.9	
	I <sub>OH</sub> = -50 μA	3 V	2.9	
V <sub>OH</sub>		4.5 V	4.4	V
	I <sub>OH</sub> = -4 mA	3 V	2.48	
	I <sub>OH</sub> = -8 mA	4.5 V	3.8	
		2 V	0.1	
	I <sub>OL</sub> = 50 μA	3 V	0.1	
V <sub>OL</sub>		4.5 V	0.1	V
	I <sub>OH</sub> = 4 mA	3 V	0.5	
	I <sub>OH</sub> = 8 mA	4.5 V	0.5	
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V	±1 <sup>(1)</sup>	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	20	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		pF

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested at VCC = 0 V.

## 5.7 Electrical Characteristics, $T_A = -40$ °C to 125°C

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	т —	SN74AHC08	UNIT
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	T <sub>A</sub>	MIN MA	X UNII
		2 V		1.9	
	I <sub>OH</sub> = -50 μA	3 V		2.9	
V <sub>OH</sub>		4.5 V		4.4	V
	I <sub>OH</sub> = -4 mA	3 V		2.48	
	I <sub>OH</sub> = -8 mA	4.5 V		3.8	
	I <sub>OL</sub> = 50 μA	2 V		(	.1
		3 V		(	.1
		4.5 V		(	.1
	I <sub>OH</sub> = 4 mA	3 V	T <sub>A</sub> = -40°C to 85°C	0.	I
V <sub>OL</sub>			T <sub>A</sub> = -40°C to125°C Recommended	(	.5 V
			T <sub>A</sub> = -40°C to 85°C	0.	14
	I <sub>OH</sub> = 8 mA	4.5 V	T <sub>A</sub> = -40°C to125°C Recommended	(	.5
I <sub>1</sub>	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V		:	±1 μA
I <sub>CC</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			20 µA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V	T <sub>A</sub> = -40°C to 85°C		10 pF



## 5.8 Switching Characteristics, $V_{CC}$ = 3.3 V ± 0.3 V

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub>	MIN	TYP	MAX	UNIT
			T <sub>A</sub> = 25°C		6.2 <sup>(1)</sup>	8.8 <sup>(1)</sup>		
		T <sub>A</sub> = - 55°C to 125°C, SN54AHC08		1 <sup>(1)</sup>	10.5 <sup>(1)</sup>			
t <sub>PLH</sub> , t <sub>PHL</sub>	A or B	Y	C <sub>L</sub> = 15 pF	T <sub>A</sub> = -40°C to 85°C, SN74AHC08		1	10.5	ns
			T <sub>A</sub> = -40°C to 125°C Recommended, SN74AHC08		1	10.5		
				T <sub>A</sub> = 25°C		8.7	12.3	
				$T_A = -55$ °C to 125°C, SN54AHC08		1	14	
t <sub>PLH</sub> , t <sub>PHL</sub> A or B Y	Y	C <sub>L</sub> = 50 pF	T <sub>A</sub> = -40°C to 85°C, SN74AHC08		1	14	ns	
			T <sub>A</sub> = -40°C to 125°C Recommended, SN74AHC08		1	14		

<sup>(1)</sup> On products compliant to MIL-PRF-38535, this parameter is not production tested.

## 5.9 Switching Characteristics, $V_{CC} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	LOAD CAPACITANCE	T <sub>A</sub>	MIN	TYP	MAX	UNIT
				T <sub>A</sub> = 25°C		4.3(1)	5.9 <sup>(1)</sup>	
			T <sub>A</sub> = - 55°C to 125°C, SN54AHC08		1(1)	7 <sup>(1)</sup>		
t <sub>PLH</sub> , t <sub>PHL</sub> A or B Y	C <sub>L</sub> = 15 pF	T <sub>A</sub> = -40°C to 85°C, SN74AHC08		1	7	ns		
				T <sub>A</sub> = -40°C to 125°C Recommended, SN74AHC08		1	7	
				T <sub>A</sub> = 25°C		5.8	7.9	
				T <sub>A</sub> = - 55°C to 125°C, SN54AHC08		1	9	
t <sub>PLH</sub> , t <sub>PHL</sub> A or B	A or B	Y	C <sub>L</sub> = 50 pF	T <sub>A</sub> = - 40°C to 85°C, SN74AHC08		1	9	ns
				T <sub>A</sub> = -40°C to 125°C Recommended, SN74AHC08		1	9	

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.



#### **5.10 Noise Characteristics**

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}^{(1)}$ 

		SN74AHC0	SN74AHC08		
		MIN MAX		UNIT	
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.8	V	
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		- 0.8	V	
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>	4.4		V	
V <sub>IH(D)</sub>	High-level dynamic input voltage	3.5		V	
V <sub>IL(D)</sub>	Low-level dynamic input voltage		1.5	V	

<sup>(1)</sup> Characteristics are for surface-mount packages only.

## **5.11 Operating Characteristics**

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$ 

	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	No load, f = 1 MHz	18	pF



## **5.12 Typical Characteristics**

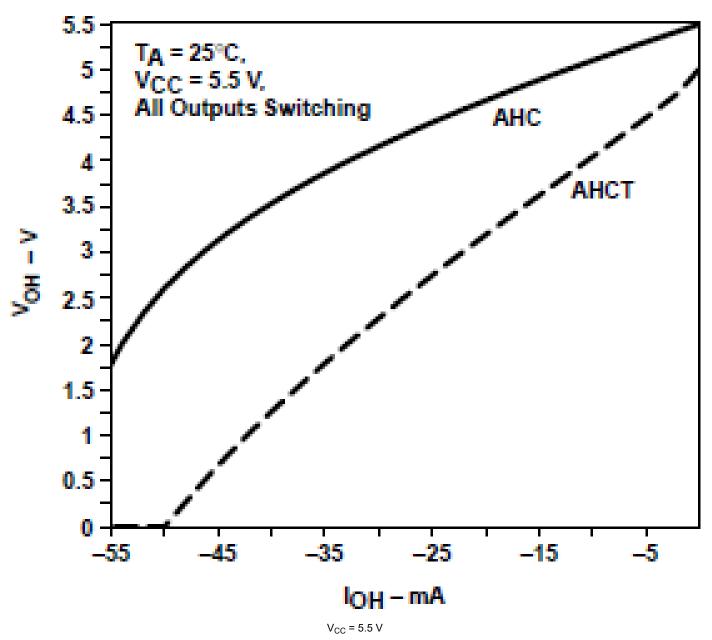
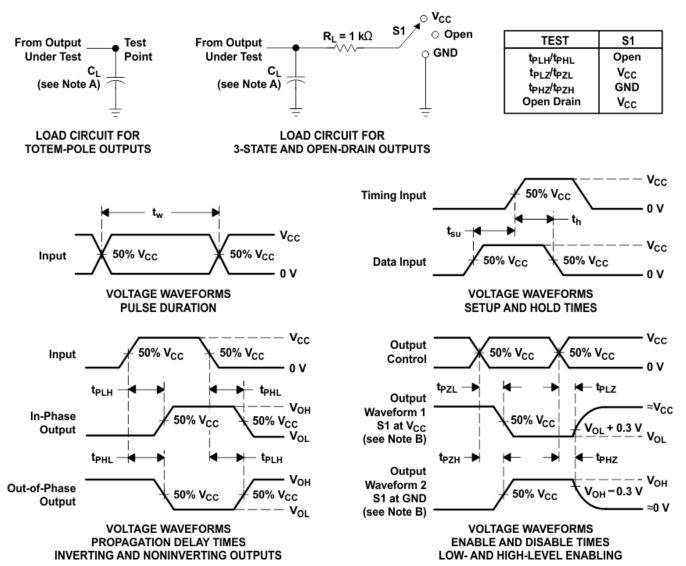


图 5-1. AHC Family V<sub>OL</sub> vs I<sub>OL</sub>



#### 6 Parameter Measurement Information



- C<sub>L</sub> includes probe and jig capacitance. A.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O$  = 50  $\Omega$ ,  $t_r \leq$  3 ns,  $t_f \leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- All parameters and waveforms are not applicable to all devices.

图 6-1. Load Circuit and Voltage Waveforms

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## 7 Detailed Description

#### 7.1 Overview

The SNx4AHC08 devices are quadruple 2-input positive-AND gates with low drive that will produce slow rise and fall times. This slow transition reduces ringing on the output signal. The inputs are high impedance when  $V_{CC} = 0 \text{ V}$ .

## 7.2 Functional Block Diagram



### 7.3 Feature Description

Slow rise and fall time on outputs allow for low-noise outputs.

#### 7.4 Device Functional Modes

表 7-1 is the function table for the SNx4AHC08.

表 7-1. Function Table (Each Gate)

INP	UTS	OUTPUT
Α	В	Υ
Н	Н	Н
L	Х	L
Х	L	L



## 8 Application and Implementation

#### 备注

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

#### 8.1 Application Information

A common application for AND gates is the use in power sequencing. Power sequencing is often employed in applications that require a processor or other delicate device with specific voltage timing requirements in order to protect the device from malfunctioning. Using the SN74AHC08 to verify that the processor has turned on can protect it from harmful signals.

#### 8.2 Typical Application

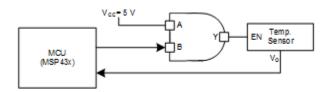


图 8-1. Typical Application Diagram

#### 8.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions must be considered to prevent ringing.

#### 8.2.2 Detailed Design Procedure

- 1. Recommended input conditions
  - Rise time and fall time specs: See ( ∆ t/ ∆ v) in the # 5.3 table.
  - Specified High and low levels: See ( $V_{IH}$  and  $V_{IL}$ ) in the # 5.3 table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid  $V_{\rm CC}$
- 2. Recommend output conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part
  - Outputs should not be pulled above V<sub>CC</sub>



#### 8.2.3 Application Curve

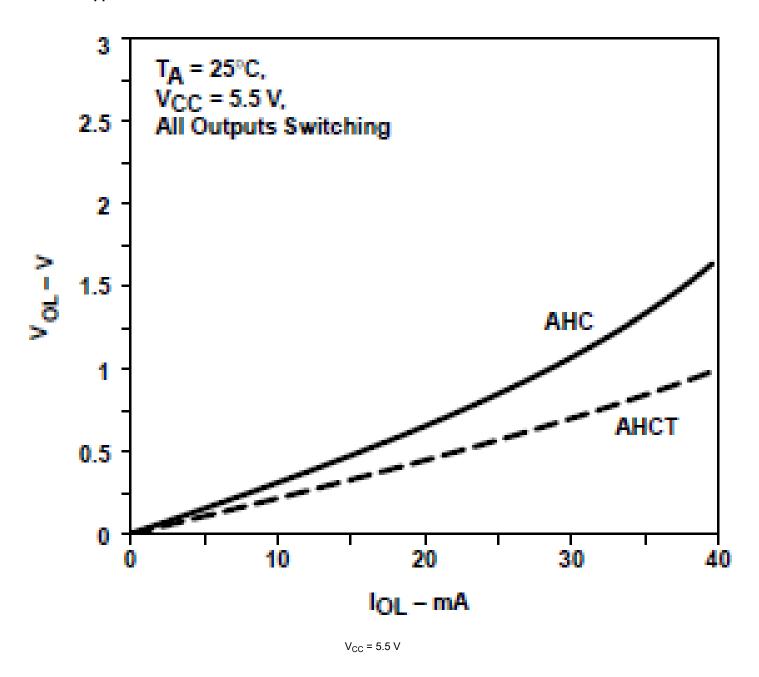


图 8-2. AHC Family V<sub>OH</sub> vs I<sub>OH</sub>

#### **Power Supply Recommendations**

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the # 5.1 table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$  F is recommended. If there are multiple  $V_{CC}$  pins, 0.01  $\mu$  F or 0.022  $\mu$  F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$  F and



1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

#### 8.3 Layout

#### 8.3.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in 🔀 8-3 are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V<sub>CC</sub>; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs, so they cannot float when disabled.

#### 8.3.1.1 Layout Example

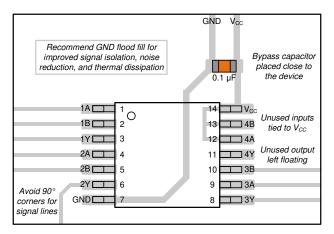


图 8-3. Layout Example for the SNx4AHC08

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English Data Sheet: SCLS236

#### 9 Device and Documentation Support

#### 9.1 Documentation Support

#### 9.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54AHC08	Click here	Click here	Click here	Click here	Click here	
SN74AHC08	Click here	Click here	Click here	Click here	Click here	

#### 9.2 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*通知* 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

#### 9.3 支持资源

TI E2E<sup>™</sup> 中文支持论坛是工程师的重要参考资料,可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题,获得所需的快速设计帮助。

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#### 9.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序,可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

#### 9.6 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

#### 10 Revision History

注:以前版本的页码可能与当前版本的页码不同

Changes from Revision K (June 2023) to Revision L (February 2024)	Page
• Updated R θ JA value: RGY = 47 to 87.1, all values in °C/W	6
Changes from Revision J (December 2015) to Revision K (June 2023)	Page
Changes from Revision J (December 2015) to Revision K (June 2023)  • 向器件信息 表中添加了 BQA 封装	

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## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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提交文档反馈

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Product Folder Links: SN54AHC08 SN74AHC08

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#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9682001Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9682001Q2A SNJ54AHC 08FK	Samples
SN74AHC08BQAR	ACTIVE	WQFN	BQA	14	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC08	Samples
SN74AHC08DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA08	Samples
SN74AHC08DGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA08	Samples
SN74AHC08DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC08	Samples
SN74AHC08N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC08N	Samples
SN74AHC08NSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC08	Samples
SN74AHC08PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	HA08	Samples
SN74AHC08PWRG4	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA08	Samples
SN74AHC08RGYR	ACTIVE	VQFN	RGY	14	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	HA08	Samples
SNJ54AHC08FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9682001Q2A SNJ54AHC 08FK	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

## PACKAGE OPTION ADDENDUM

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**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54AHC08, SN74AHC08:

Catalog: SN74AHC08

■ Enhanced Product : SN74AHC08-EP. SN74AHC08-EP

Military: SN54AHC08

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

• Enhanced Product - Supports Defense, Aerospace and Medical Applications

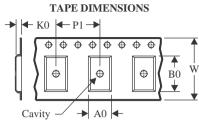
• Military - QML certified for Military and Defense Applications



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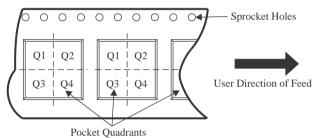
#### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC08BQAR	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1
SN74AHC08DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74AHC08DGVR	TVSOP	DGV	14	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
SN74AHC08DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC08DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74AHC08NSR	so	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74AHC08PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC08PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC08PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC08RGYR	VQFN	RGY	14	3000	330.0	12.4	3.75	3.75	1.15	8.0	12.0	Q1



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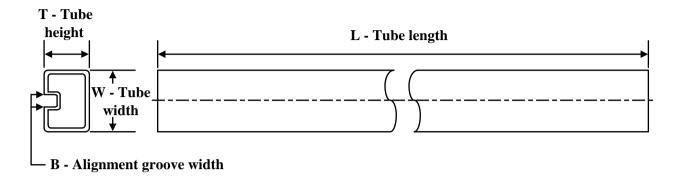
\*All dimensions are nominal

ii aiiiiaiiai							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC08BQAR	WQFN	BQA	14	3000	210.0	185.0	35.0
SN74AHC08DBR	SSOP	DB	14	2000	356.0	356.0	35.0
SN74AHC08DGVR	TVSOP	DGV	14	2000	356.0	356.0	35.0
SN74AHC08DR	SOIC	D	14	2500	353.0	353.0	32.0
SN74AHC08DR	SOIC	D	14	2500	356.0	356.0	35.0
SN74AHC08NSR	so	NS	14	2000	356.0	356.0	35.0
SN74AHC08PWR	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC08PWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74AHC08PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
SN74AHC08RGYR	VQFN	RGY	14	3000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9682001Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
SN74AHC08N	N	PDIP	14	25	506	13.97	11230	4.32
SN74AHC08N	N	PDIP	14	25	506	13.97	11230	4.32
SNJ54AHC08FK	FK	LCCC	20	55	506.98	12.06	2030	NA

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

## D (R-PDSO-G14)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



### DB (R-PDSO-G\*\*)

### PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**

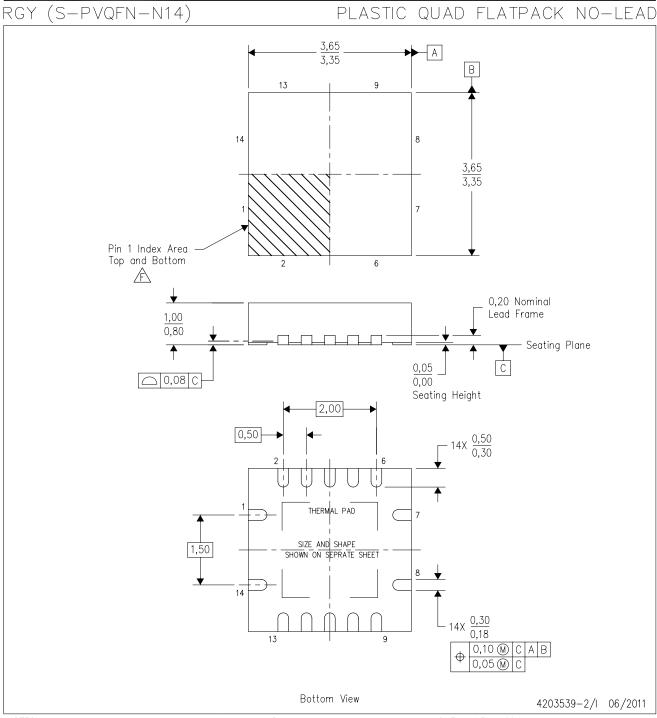


NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



## RGY (S-PVQFN-N14)

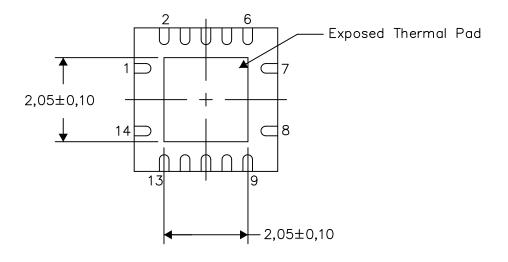
### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

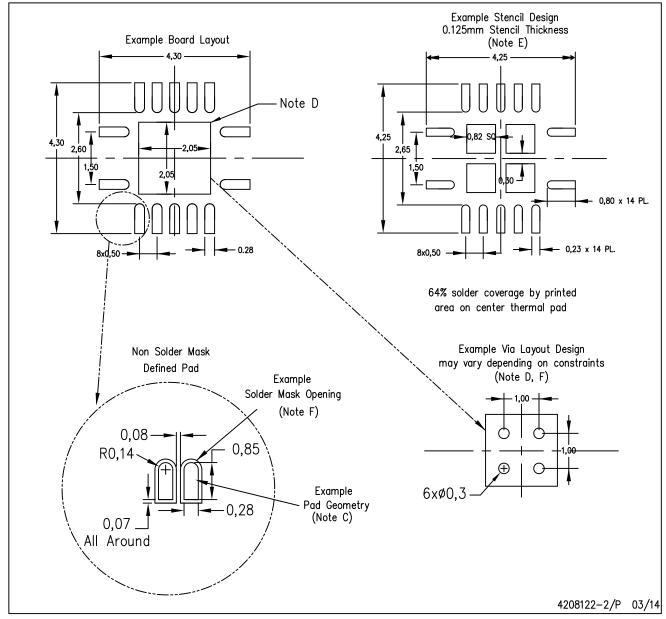
4206353-2/P 03/14

NOTE: All linear dimensions are in millimeters



# RGY (S-PVQFN-N14)

## PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">http://www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



2.5 x 3, 0.5 mm pitch

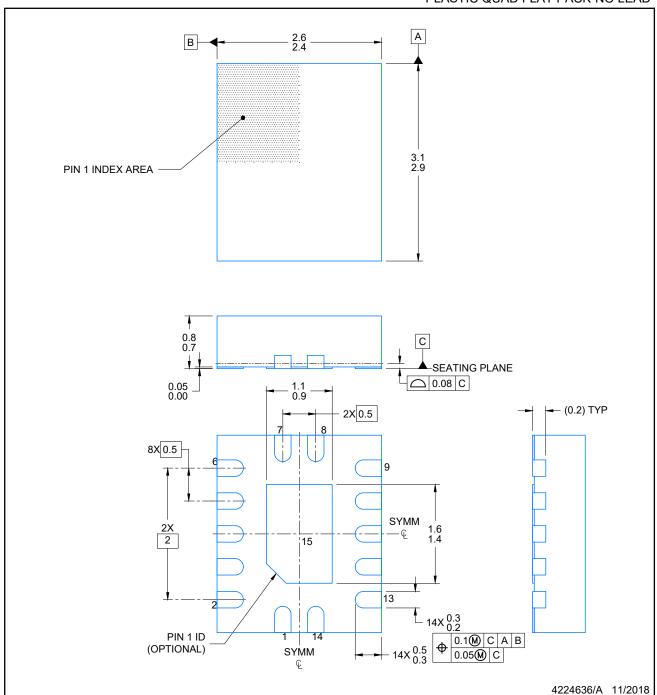
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



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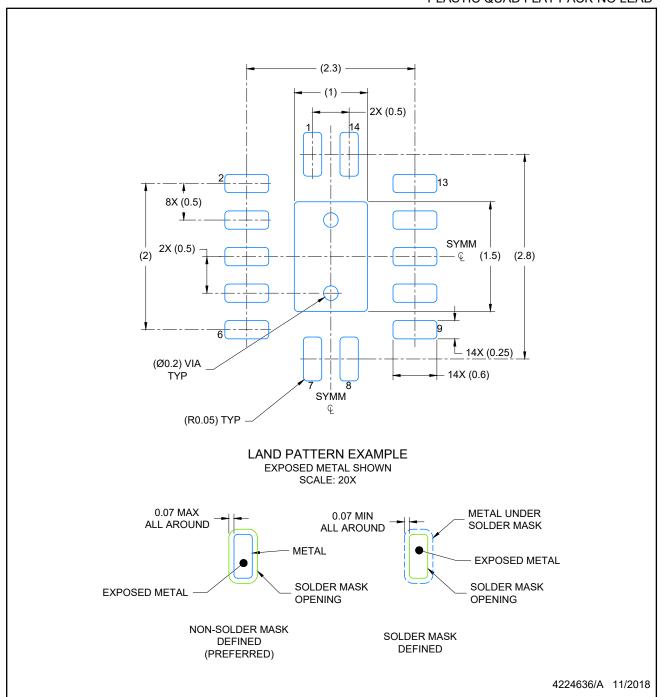
PLASTIC QUAD FLAT PACK-NO LEAD



- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



PLASTIC QUAD FLAT PACK-NO LEAD

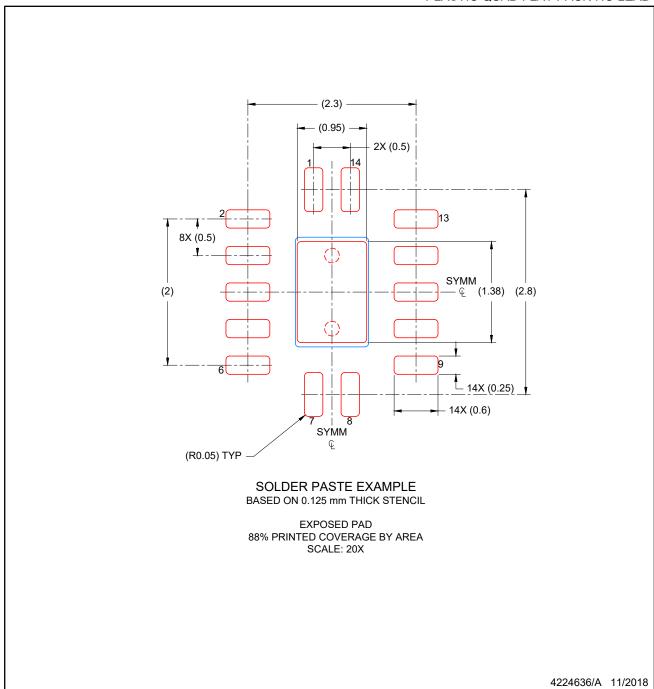


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLAT PACK-NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



### **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### DGV (R-PDSO-G\*\*)

#### 24 PINS SHOWN

#### **PLASTIC SMALL-OUTLINE**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

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